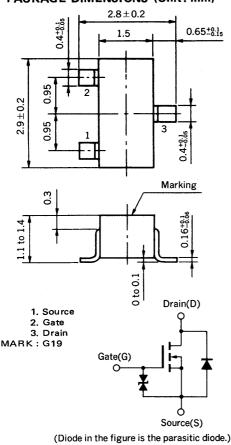


N-CHANNEL MOS FET FOR SWITCHING

PACKAGE DIMENSIONS (Unit: mm)



The 2SK1657 is an N-channel vertical type MOS FET which can be driven by 2.5 V power supply.

As the MOS FET is low Gate Leakage Current, it is suitable for filter circuit.

FEATURES

- Directly driven by ICs having a 3 V power supply.
- Has low Gate Leakage Current
 I_{GSS} = ±5 nA MAX. @ V_{GS} = ±3.0 V

QUALITY GRADE

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

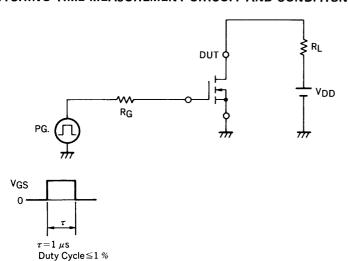
ABSOLUTE MAXIMUM RATINGS ($T_a = 25$ °C)

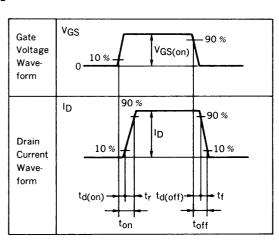
PARAMETER	SYMBOL	RATINGS	UNIT	TEST CONDITIONS	
Drain to Source Voltage	V _{DSS}	30	V	V _{GS} = 0	
Gate to Source Voltage	V _{GSS}	±7	V	V _{DS} = 0	
Drain Current	ID(DC)	±100	mA		
Drain Current	1 _D (pulse)	±200	mA	PW ≦ 10 ms, Duty Cycle ≦ 50 %	
Total Power Dissipation	PT	200	mW		
Channel Temperature	T _{ch}	150	°c		
Operating Temperature	T _{opt}	-55 to +80	°C		
Storage Temperature	T _{stg}	-55 to +150	°C		

ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

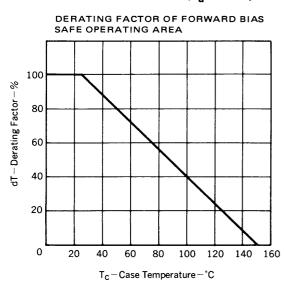
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain Cut-off Current	IDSS			10	μА	V _{DS} = 30 V, V _{GS} = 0
Gate Leakage Current	IGSS			±5.0	nA	V _{GS} = ±3.0 V, V _{DS} = 0
Gate Cut-off Voltage	V _{GS} (off)	0.9	1,2	1,5	V	V _{DS} = 3.0 V, I _D = 1.0 μA
Forward Transfer Admittance	ly _{fs} l	20	40		mS	V _{DS} = 3.0 V, I _D = 10 mA
Drain to Source On-State Resistance	RDS(on)1		25	45	Ω	V _{GS} = 2.5 V, I _D = 10 mA
Drain to Source On-State Resistance	R _{DS} (on)2		18	25	Ω	V _{GS} = 4.0 V, I _D = 10 mA
Input Capacitance	Ciss		15		pF	V _{DS} = 3.0 V, V _{GS} = 0, f = 1 MHz
Output Capacitance	Coss		10		pF	
Feedback Capacitance	C _{rss}		1.5		pF	
Turn-On Delay Time	^t d(on)		95		ns	V_{DD} = 3.0 V, I_{D} = 10 mA $V_{GS(on)}$ = 3 V, R_{G} = 10 Ω R_{L} = 300 Ω
Rise Time	t _r		360		ns	
Turn-Off Delay Time	^t d(off)		160		ns	
Fall Time	t _f		150		ns	

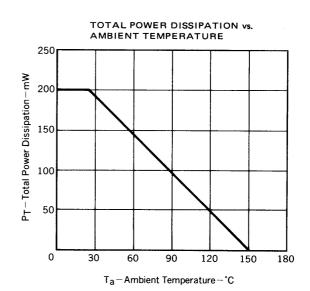
SWITCHING TIME MEASUREMENT CIRCUIT AND CONDITIONS



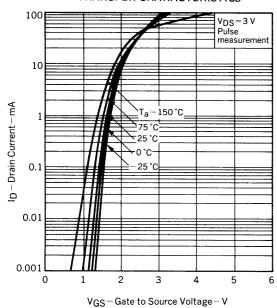


TYPICAL CHARACTERISTICS (T_a = 25 °C)

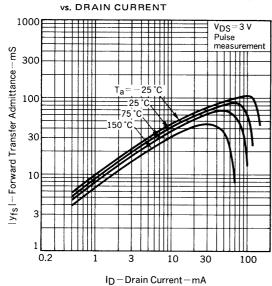




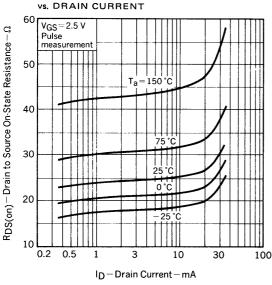
TRANSFER CHARACTERISTICS



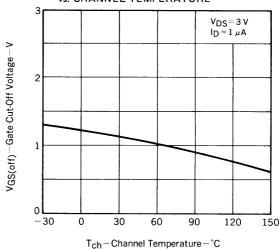
FORWARD TRANSFER ADMITTANCE



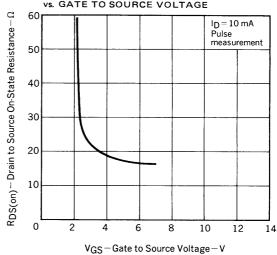
DRAIN TO SOURCE ON-STATE RESISTANCE



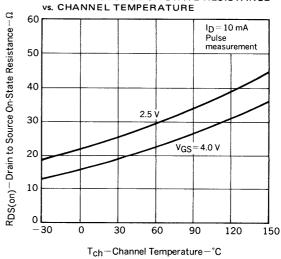
GATE TO SOURCE CUTOFF VOLTAGE vs. CHANNEL TEMPERATURE

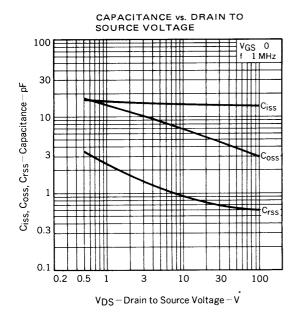


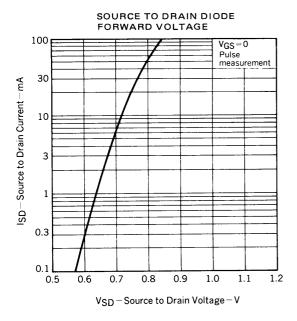
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

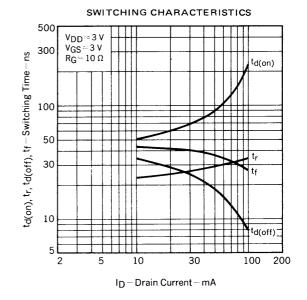


DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE











RECOMMENDED SOLDERING CONDITIONS

Mounting of this product by soldering should be done under the following conditions.

Please consult our representatives about soldering methods and conditions other than these.

SURFACE MOUNT TYPE

For details of the recommended soldering conditions, see the information document "SMT MANUAL" (IEI-1207).

Soldering Method	Soldering Conditions	Symbol for Recommended Conditions		
Infrared Reflow	Package peak temp.: 230 °C Soldering time: within 30 sec (above 210 °C) Soldering times: 1, Days limitation: none*	IR30-00		
Vapor Phase Soldering	Package peak temp.: 215 °C Soldering time: within 40 sec (above 200 °C) Soldering times: 1, Days limitation: none*	VP15-00		
Soldering bath temp.: below 260 °C Wave Soldering Soldering time: within 10 sec Soldering times: 1, Days limitation: none*		WS60-00		

^{*:} Stored days under storage conditions at 25 $^{\circ}$ C and below 65 % R.H. after the dry-pack has been opened. Note 1 Combination of soldering methods should be avoided.

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Application examples recomended by NEC Corporation

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Measurement equipment, Audio and Video equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Communication equipment (trunk line), Train and

Traffic control devices, industrial robots, Burning control systems, antidisaster systems, anticrime

systems etc.

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